A8501

# 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect 

## Not for New Design

These parts are in production but have been determined to be NOT FOR NEW DESIGN. This classification indicates that sale of this device is currently restricted to existing customer applications. The device should not be purchased for new design applications because obsolescence in the near future is probable. Samples are no longer available.

Date of status change: December 5, 2018

## Recommended Substitutions:

For existing customer transition, and for new customers or new applications, refer to the ALT80600.

NOTE: For detailed information on purchasing options, contact your local Allegro field applications engineer or sales representative.

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A8501

# 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect 

## FEATURES AND BENEFITS

- 600 kHz to 2.2 MHz switching frequency-ability to operate above the AM band
- Internal bias supply for single-supply operation $\left(\mathrm{V}_{\mathrm{IN}}=6.8\right.$ to 21 V )
- Boost converter with integrated 40 V DMOS switch and OVP-load-dump protection
- $3.5 \mu \mathrm{~A}$ shutdown current-limits battery drain
- Active current sharing between LED strings for $0.8 \%$ current matching and $0.7 \%$ accuracy
- Drive up to 9 series LEDs in 4 parallel strings, 36 LEDs $\operatorname{maximum}\left(\mathrm{V}_{\mathrm{f}}=3.5 \mathrm{~V}, \mathrm{I}_{\mathrm{f}}=100 \mathrm{~mA}\right)$
- LED sinks rated for 100 mA each ( 400 mA total)
- PWM dimming with LED PWM duty cycle control
- 4000:1 dimming range
- Extensive fault mode protection schemes:
$\square$ Shorted LED protection against misconnected loadswith true output disconnect
$\square$ Open LED disconnect protects against LED failures
$\square$ External thermistor sensing to limit LED temperature
$\square$ Output overvoltage protection (OVP): 19.5 V default can be adjusted as high as 38 V
$\square$ Open Schottky and open OVP resistor protection against external component failure
$\square$ Input under- and overvoltage protection (UVLO and OVLO) against $\mathrm{V}_{\text {IN }}$ variation
$\square$ Boost current limit, output short circuit limit, overtemperature protection (OTP), and soft start


## Package:

28-pin TSSOP with exposed thermal pad (package LP)

## DESCRIPTION

The A8501 is a multioutput WLED/RGB driver for backlighting medium-size displays. The A8501 integrates a boost converter and four 100 mA current sinks. LED channels can be tied together for up to 400 mA sink capability. It can work from a single power supply of 6.8 to 21 V and withstand up to 40 V . The boost converter is a constant frequency, current-mode converter.

Operating frequency can be set to 2 MHz in order to avoid interference with the AM radio band. The integrated boost DMOS switch is rated for 40 V at 3.6 A . PWM dimming allows LED currents to be controlled at up to a 1000:1 ratio. Additional 4:1 dimming can be achieved by using the DIM pin.

TheA8501 provides protection against output connector shorts through an integrated output disconnect switch. An optional external thermistor can be used to limit LED current based on panel temperature.

The device is supplied in a surface mount, 28-pin TSSOP package (suffix LP), with exposed thermal pad for enhanced thermal dissipation. It is lead $(\mathrm{Pb})$ free, with a leadframe plating choice of $100 \%$ matte-tin (suffix T) or tin-bismuth (suffix B).

## Applications

- GPS navigation systems
- Automotive infotainment
- Back-up camera displays
- Cluster backlighting
- Portable DVD players
- Industrial LCD displays

Figure 1: LCD monitor backlight driving 4 LED strings. On/off and dimming control using ENABLE pin.

- Current $=50 \mathrm{~mA}$ per string
- OVP = 35 V nominal
- Switching frequency $=\mathbf{2 M H z}$


Optional Configuration for Thermal Derating


# 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect 

## SPECIFICATIONS

## Selection Guide

| Part Number | Operating <br> Temperature, $\mathrm{T}_{\mathbf{A}}$ | Packing | Package | Leadframe Plating |
| :---: | :---: | :---: | :---: | :---: |
| A8501ELPTR-T | $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ | 4000 pieces per 13 -in. reel | $28-$ pin TSSOP with exposed thermal pad | $100 \%$ matte tin |
| A8501KLPTR-T | $-40^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$ |  |  |  |

## Absolute Maximum Ratings*

| Characteristic | Symbol | Notes | Rating | Units |
| :---: | :---: | :---: | :---: | :---: |
| SW, OVP, CAP, OUT Pins |  |  | -0.3 to 40 | V |
| LED1 through LED4 Pins |  |  | -0.3 to 21 | V |
| VIN Pin | $\mathrm{V}_{\text {IN }}$ | Steady state | -0.3 to 34 | V |
|  |  | Transient < 1 s | 40 | V |
| DIM Pin | $\mathrm{V}_{\text {DIM }}$ |  | -0.3 to 6 | V |
| Remaining Pins |  |  | -0.3 to 7 | V |
| Operating Ambient Temperature | $\mathrm{T}_{\text {A }}$ | Range E | -40 to 85 | ${ }^{\circ} \mathrm{C}$ |
|  |  | Range G | -40 to 105 | ${ }^{\circ} \mathrm{C}$ |
|  |  | Range K | -40 to 125 | ${ }^{\circ} \mathrm{C}$ |
| Maximum Junction Temperature | $\mathrm{T}_{\mathrm{J}}(\mathrm{max})$ |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | $\mathrm{T}_{\text {stg }}$ |  | -55 to 150 | ${ }^{\circ} \mathrm{C}$ |

*Stresses beyond those listed in this table may cause permanent damage to the device. The absolute maximum ratings are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics table is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Thermal Characteristics

| Characteristic | Symbol | Test Conditions* | Value | Units |
| :---: | :---: | :--- | :---: | :---: |
| Package Thermal Resistance | $R_{\theta J A}$ | 4-layer PCB based on JEDEC standard | 28 |  |
| ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |  |  |  |  |

[^0]
## 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect



Functional Block Diagram

## $2 \mathrm{MHz}, 4$ Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect

| BIAS 1 | PAD |  |  | 28 EN |
| :---: | :---: | :---: | :---: | :---: |
| dgnd 2 |  |  |  | 27 SEL2 |
| dıM 3 |  |  |  | 26 seL 1 |
| sw 4 |  |  |  | 25 PGND |
| sw 5 |  |  |  | 24 PGND |
| sw 6 |  |  |  | 23 PGND |
| ovp 7 |  |  |  | 22 NC |
| CAP 8 |  |  |  | 21 VIN |
| AGND 9 |  |  |  | 20 COMP |
| ISET 10 |  |  |  | 19 FSET |
| VT1 11 |  |  |  | 18 OUT |
| vto 12 |  |  |  | 17 LED 4 |
| LED1 13 |  |  |  | 16 Led3 |
| LED2 14 |  |  |  | 15 LGND |

## Pin-out Diagram

Terminal List Table

| Number | Name | Function |
| :---: | :---: | :---: |
| 1 | BIAS | Output of internal 6 V bias supply. Decouple with a $0.1 \mu \mathrm{~F}$ ceramic capacitor to DGND. |
| 2 | DGND | Digital signal ground. Connect AGND, DGND, LGND, PGND, and PAD using star ground connection. |
| 3 | DIM | Sets $I_{\text {LED }}$ by adjusting the $I_{\text {SET }}$ to $I_{\text {LEDX }}$ current gain, $\mathrm{A}_{\text {ISET }}$. When $D I M=\mathrm{V}_{\text {IL }}, \mathrm{A}_{\text {ISET }}=$ 960 and when $\mathrm{DIM}=\mathrm{V}_{I H}, \mathrm{~A}_{\text {ISET }}=240$. |
| 4, 5, 6 | SW | DMOS switch drain node. Tie these three pins together on the PCB. |
| 7 | OVP | To enable overvoltage protection, connect this pin through a resistor to the CAP pin. The default OVP level, with $0 \Omega$ resistor, is 19.5 V . External resistor can set OVP up to 38 V . |
| 8 | CAP | Input connection for output disconnect switch. |
| 9 | AGND | Analog signal ground. Connect AGND, DGND, LGND, PGND, and PAD using star ground connection. |
| 10 | ISET | Sets the $100 \%$ current level through LED strings. Set by value of RISET connected between ISET and AGND. |
| 11 | VTI | ISET voltage override. Sets the ISET voltage when $\mathrm{V}_{\mathrm{TI}}<1.23 \mathrm{~V}$. Tie directly to VTO pin to disable this feature. This pin can be used for LED current thermal derating or external analog LED current control. See the Typical Application Circuits section for additional information. |
| 12 | VTO | 2.46 V output voltage. Use this voltage to bias an external NTC resistor or as a DAC reference. This pin can be used as a logic high signal for the SEL and DIM pins. |
| 13,14,16,17 | LEDX | LED current sinks. |
| 15 | LGND | Power ground for LED current sinks. Connect AGND, DGND, LGND, PGND, and PAD using star ground connection. |
| 18 | OUT | Output connection for output disconnect switch. Connect LED common connection to this pin. |
| 19 | FSET | Connect RFSET between FSET and AGND to set boost switching frequency. |
| 20 | COMP | Sets boost loop compensation. Connect external compensation capacitor between COMP and AGND for boost converter stability. |
| 21 | VIN | Input supply for the device. Decouple with a $0.1 \mu \mathrm{~F}$ ceramic capacitor. |
| 22 | NC | Not connected internally. It is recommended to connect this pin to external ground. |
| 23, 24, 25 | PGND | Power ground. Connect AGND, DGND, LGND, PGND, and PAD using star ground connection. |
| 26 | SEL1 | SEL1 and SEL2 together select which LED strings are enabled. See Functional |
| 27 | SEL2 | Description section. |
| 28 | EN | Enable and PWM LED current control. Apply logic-level PWM for PWM-controlled dimming mode. |
| - | PAD | Exposed thermal pad. Connect AGND, DGND, LGND, PGND, and PAD using star ground connection. Connect to PCB copper layer for enhanced heat dissipation. |

## 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect

ELECTRICAL CHARACTERISTICS: valid using circuit shown in figure 1; $\mathrm{V}_{\mathrm{IN}}=12 \mathrm{~V}$, EN=SEL1=SEL2=5 V, $R_{\text {ISET }}=12.4 \mathrm{k} \Omega, \mathrm{R}_{\mathrm{FSET}}=24.3 \mathrm{k} \Omega$, VTO shorted to VTI guaranteed over the full operating temperature range with $\mathrm{T}_{\mathrm{A}}=\mathrm{T}_{\mathrm{J}}$, typical specifications are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$; unless otherwise noted

| Characteristics | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| General |  |  |  |  |  |  |
| Input Voltage Range | $\mathrm{V}_{\text {IN }}$ |  | 8 | - | 21 | V |
| Undervoltage Lockout Threshold | $\mathrm{V}_{\text {UVLO(th) }}$ | $\mathrm{V}_{\text {IN }}$ falling | 5.7 | 6.5 | 6.8 | V |
| UVLO Hysteresis Window | $\mathrm{V}_{\text {UVLO(hys) }}$ |  | 0.21 | 0.55 | 0.81 | V |
| Overvoltage Lockout Threshold | $\mathrm{V}_{\text {OVLO(th) }}$ | $\mathrm{V}_{\text {IN }}$ rising | 29 | 32 | 34 | V |
| Supply Current | $I_{s}$ | 2 MHz switching at no load | 4 | 11 | 15 | mA |
|  |  | $\begin{aligned} & \mathrm{EN}=\mathrm{V}_{\mathrm{IL}}, \text { in shutdown, } \mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \\ & \mathrm{CAP}=\mathrm{VIN}=\mathrm{SW}=\mathrm{OVP}=16 \mathrm{~V} \\ & \mathrm{I}_{\mathrm{S}}=\mathrm{I}_{\mathrm{VIN}}+\mathrm{I}_{\mathrm{SW}}+\mathrm{I}_{\mathrm{CAP}}+\mathrm{I}_{\mathrm{OVP}} \\ & \hline \end{aligned}$ | - | 3.5 | 6 | $\mu \mathrm{A}$ |
|  |  | $\begin{aligned} & \mathrm{EN}=\mathrm{V}_{\mathrm{IL}}, \text { in shutdown, } \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to } 125^{\circ} \mathrm{C}, \\ & \mathrm{CAP}=\mathrm{VIN}=\mathrm{SW}=\mathrm{OVP}=16 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{S}}=\mathrm{I}_{\mathrm{VIN}}+\mathrm{I}_{\mathrm{SW}}+\mathrm{I}_{\mathrm{CAP}}+\mathrm{I}_{\mathrm{OVP}} \\ & \hline \end{aligned}$ | - | 3.5 | 10 | $\mu \mathrm{A}$ |
|  |  | $\mathrm{EN}=\mathrm{V}_{\mathrm{IL}}$, not in shutdown, $\mathrm{I}_{\mathrm{S}}=\mathrm{I}_{\mathrm{VIN}}$ | - | 2 | 4 | mA |
| Logic Input levels (DIM, EN, SELx Pins) |  |  |  |  |  |  |
| Input Voltage Level-Low | $\mathrm{V}_{\text {IL }}$ |  | - | - | 0.4 | V |
| Input Voltage Level-High | $\mathrm{V}_{\mathrm{IH}}$ |  | 1.5 | - | - | V |
| Input Leakage Current (EN, DIM pins) | $\mathrm{I}_{\text {kg1 }}$ | $\mathrm{V}_{\text {DIM }}, \mathrm{V}_{\text {EN }}=5 \mathrm{~V}$ | 30 | 50 | 70 | $\mu \mathrm{A}$ |
| Input Leakage Current (SELx pins) | $\mathrm{I}_{\text {kg2 }}$ | $\mathrm{V}_{\text {SELX }}=5 \mathrm{~V}$ | - | - | 1 | $\mu \mathrm{A}$ |
| Overvoltage Protection |  |  |  |  |  |  |
| Output Overvoltage Threshold | $\mathrm{V}_{\text {OVP(th) }}$ | OVP pin connected to OUT pin | 18 | 19.5 | 21 | V |
| OVP Sense Current | lovph |  | 183 | 200 | 217 | $\mu \mathrm{A}$ |
| OVP Leakage Current | $\mathrm{I}_{\text {OVP(Ikg) }}$ | $\mathrm{V}_{\text {OVP }}=18 \mathrm{~V}, \mathrm{EN}=\mathrm{V}_{\mathrm{IL}}$, in shutdown | - | 0.1 | 1 | $\mu \mathrm{A}$ |
| Boost Switch |  |  |  |  |  |  |
| Switch On Resistance | $\mathrm{R}_{\text {SWDS(on) }}$ | $\mathrm{I}_{\text {SW }}=2 \mathrm{~A}$ | 40 | 100 | 300 | $\mathrm{m} \Omega$ |
| Switch Leakage Current | $\mathrm{I}_{\text {SW(kg) }}$ | $\mathrm{V}_{\text {SW }}=21 \mathrm{~V}$ | - | 0.1 | 10 | $\mu \mathrm{A}$ |
| Switch Current Limit | $\mathrm{I}_{\text {SW(lim) }}$ |  | 3 | 3.6 | 5.3 | A |
| LED Current Sinks |  |  |  |  |  |  |
| LEDx Regulation Voltage | $\mathrm{V}_{\text {LED }}$ | $\mathrm{V}_{\text {LED } 1}=\mathrm{V}_{\text {LED2 }}=\mathrm{V}_{\text {LED } 3}=\mathrm{V}_{\text {LED4 }}$ | - | 750 | 1100 | mV |
| $\mathrm{I}_{\text {ISET }}$ to $\mathrm{I}_{\text {LEDx }}$ Current Gain | $\mathrm{A}_{\text {ISET }}$ | $\mathrm{I}_{\text {ISET }}=100 \mu \mathrm{~A}, \mathrm{DIM}=\mathrm{V}_{\text {IL }}$ | 914 | 960 | 1008 | A/A |
|  |  | $\mathrm{I}_{\text {ISET }}=100 \mu \mathrm{~A}, \mathrm{DIM}=\mathrm{V}_{\text {IH }}$ | 228 | 240 | 252 | A/A |
| ISET Pin Voltage | $\mathrm{V}_{\text {ISET }}$ |  | 1.13 | 1.235 | 1.34 | V |
| VTO Pin Voltage | $\mathrm{V}_{\text {TO }}$ | $\mathrm{I}_{\mathrm{VTO}}=1 \mathrm{~mA}$ | 2.00 | 2.46 | 2.65 | V |
| VTO Pin Current Maximum | $\mathrm{I}_{\mathrm{TO}(\text { max })}$ | $\mathrm{I}_{\mathrm{VTO}}$ increased until $\mathrm{V}_{\text {TO }}$ drops by $1 \%$ | 1.5 | 2.4 | 5 | mA |
| VTI Pin Voltage | $\mathrm{V}_{\text {Tl(falling) }}$ | $\mathrm{V}_{\mathrm{T},}$ start $>1.34 \mathrm{~V}$, VTI pin voltage decreasing before control changes to VTI pin | 1.00 | 1.12 | 1.23 | V |
|  | $\mathrm{V}_{T \backslash(\text { rising })}$ | $\mathrm{V}_{\mathrm{T} I}$ start $<1 \mathrm{~V}$ VTI pin increasing before changing to internal reference | 1.13 | 1.235 | 1.34 | V |
| ISET Pin Allowable Current Range | $\mathrm{I}_{\text {ISET }}$ |  | 20 | - | 100 | $\mu \mathrm{A}$ |

Continued on the next page...

## 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect

ELECTRICAL CHARACTERISTICS (continued): valid using circuit shown in figure 1; $\mathrm{V}_{\text {IN }}=12 \mathrm{~V}$, $\mathrm{EN}=\mathrm{SEL} 1=\mathrm{SEL} 2=5 \mathrm{~V}, \mathrm{R}_{\text {ISET }}=12.4 \mathrm{k} \Omega, \mathrm{R}_{\text {FSET }}=24.3 \mathrm{k} \Omega$, VTO shorted to VTI guaranteed over the full operating temperature range with $T_{A}=T_{J}$, typical specifications are at $T_{A}=25^{\circ} \mathrm{C}$; unless otherwise noted

| Characteristics | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| LEDx Accuracy ${ }^{1}$ | Err ${ }_{\text {Led }}$ | RISET $=12.4 \mathrm{k} \Omega .100 \%$ current ratio, measured as the average of $\mathrm{V}_{\text {LEDx }}$, for LED1 through LED4, with $\mathrm{V}_{\text {LEDx }}=0.75 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\mathrm{J}}=0$ to $125^{\circ} \mathrm{C}$ | - | 0.7 | 3 | \% |
| LEDx Matching ${ }^{2}$ | $\Delta_{\text {LEDx }}$ | $\begin{aligned} & l_{\text {ISET }}=100 \mu \mathrm{~A}, 100 \% \text { current ratio, with } \\ & \mathrm{V}_{\text {LEDx }}=0.75 \mathrm{~V} \end{aligned}$ | - | 0.8 | 3 | \% |
| LED Switch Leakage Current | $\mathrm{I}_{\text {S(kg) }}$ | $\mathrm{V}_{\text {LEDx }}=17.5 \mathrm{~V}, \mathrm{EN}=\mathrm{V}_{\text {IL }}=0 \mathrm{~V}$ | 4.8 | 8.75 | 12.8 | $\mu \mathrm{A}$ |
| LEDx Short Detect Voltage Threshold | $\mathrm{V}_{\text {LEDSC }}$ | On any LEDx pin, forces latched shutdown | 17.5 | 19 | 21 | V |
| Output Disconnect Switch On-Resistance | $\mathrm{R}_{\text {ODS(on) }}$ | $\mathrm{V}_{\text {IN }}=8 \mathrm{~V}, \mathrm{I}_{\text {OUT }}=400 \mathrm{~mA}, \mathrm{~T}_{J}=125^{\circ} \mathrm{C}$ | - | 2 | 4 | $\Omega$ |
| Oscillator |  |  |  |  |  |  |
| FSET Pin Voltage | $\mathrm{V}_{\text {FSET }}$ | $\mathrm{R}_{\text {FSET }}=24.3 \mathrm{k} \Omega$ | 1.14 | 1.235 | 1.33 | V |
| Frequency | $\mathrm{f}_{\text {OSC }}$ | $\mathrm{R}_{\text {FSET }}=24.3 \mathrm{k} \Omega$ | 1.8 | 2.1 | 2.4 | MHz |
|  |  | $\mathrm{R}_{\text {FSET }}=51.1 \mathrm{k} \Omega$ | 0.850 | 1 | 1.285 | MHz |
|  |  | $\mathrm{R}_{\text {FSET }}=84.5 \mathrm{k} \Omega$ | 0.5 | 0.6 | 0.8 | MHz |
| Minimum Switch Off-Time | $\mathrm{t}_{\text {off(min) }}$ |  | - | 60 | 110 | ns |
| Minimum Switch On-Time | $\mathrm{t}_{\text {on(min) }}$ |  | - | 60 | 110 | ns |
| Soft Start |  |  |  |  |  |  |
| Soft Start Boost Current Limit | $\mathrm{I}_{\text {SWSS(lim) }}$ | Initial soft start current for boost switch | 0.4 | 0.6 | 0.75 | A |
| Soft Start LEDx Current | l ledss | Current through each enabled LEDx pin during soft start, $\mathrm{R}_{\text {ISET }}=12.4 \mathrm{k} \Omega$ | 3 | 5 | 10 | mA |
| PWM Timing on EN pin |  |  |  |  |  |  |
| Maximum PWM Dimming Off-Time | $t_{\text {PwmL }}$ | Measured while EN = low, during dimming control, and internal references are powered on (exceeding $\mathrm{t}_{\text {PWML }}$ results in shutdown) | - | 131,072 | - | $\mathrm{f}_{\text {Sw }}$ cycles |
| Minimum PWM On-Time | $\mathrm{t}_{\text {PWM }}$ |  | - | - | 6 | $\mu \mathrm{s}$ |
| PWM High to LED On Delay | $\mathrm{t}_{\text {dPWM(on) }}$ | Time between PWM enable and when LED current reaches $90 \%$ of maximum, with internal references enabled and $t_{\text {PWML }}$ not exceeded | - | 3 | - | $\mu \mathrm{s}$ |
| PWM Low to LED Off Delay | $\mathrm{t}_{\text {dPWM(off) }}$ | Time between EN going low and when LED current reaches $10 \%$ of maximum, with internal references enabled and $t_{\text {PWML }}$ not exceeded | - | 0.5 | - | $\mu \mathrm{s}$ |
| Thermal Shutdown Threshold ${ }^{3}$ | $\mathrm{T}_{\text {TSD }}$ | Device temperature rising | 150 | 172 | 195 | ${ }^{\circ} \mathrm{C}$ |
| Thermal Shutdown Hysteresis ${ }^{3}$ | $\mathrm{T}_{\text {TSD(hys) }}$ |  | 15 | 20 | 25 | ${ }^{\circ} \mathrm{C}$ |

${ }^{1}$ LED accuracy is defined as $\left(I_{\text {ISET }} \times 960-I_{\text {LED }}(a v)\right) /\left(I_{\text {ISET }} \times 960\right)$, $\mathrm{I}_{\text {LED }}(\mathrm{av})$ measured as the average of $\mathrm{I}_{\text {LED } 1}$ through $\mathrm{I}_{\text {LED4 }}$.
${ }^{2}$ LED current matching is defined as $\left(I_{\text {LEDX }}-I_{\text {LED }}(\mathrm{av})\right) / I_{\text {LED }}(\mathrm{av})$, with $\mathrm{I}_{\mathrm{LED}}(\mathrm{av})$ as defined in footnote 1.
${ }^{3}$ Guaranteed by design and characterization, functional tested in production.

## PERFORMANCE CHARACTERISTICS

Electrostatic Discharge Structures Equivalent ESD on Pins


AGND, LGND, PGND, and DGND xGND


ISET, VTO, and VTI


SEL1, SEL2, and EN


## PERFORMANCE CHARACTERISTICS

## PWM Waveforms

$\mathrm{V}_{\mathrm{BAT}}=12 \mathrm{~V}, \mathrm{I}_{\mathrm{OUT}}=400 \mathrm{~mA}, \mathrm{f}_{\mathrm{PWM}}=200 \mathrm{~Hz}$
4 channels enabled, 6 LEDs each channel


| Symbol | Parameter | Units/Division |
| :---: | :---: | :---: |
| C1 | V BAT $^{\text {BAT }}$ | 5 V |
| C2 | V OUT | 20 V |
| C3 | I OUT | 500 mA |
| C4 | I BAT | 500 mA |
| t | time | 20 ms |

1\% PWM Duty Cycle (Startup)


# $2 \mathrm{MHz}, 4$ Channel $\times 100$ m A WLED/RGB Driver with Output Disconnect 

## PERFORMANCE CHARACTERISTICS <br> Startup Waveforms

Soft Start Turn On Using Rising $\mathrm{V}_{\mathrm{BAT}}$
$\mathrm{V}_{\mathrm{EN}}=5 \mathrm{~V}, \mathrm{~V}_{\mathrm{BAT}}=0 \mathrm{~V}$ to $12 \mathrm{~V}, \mathrm{I}_{\mathrm{OUT}}=400 \mathrm{~mA}$
4 channels enabled, 6 series LEDs each


| Symbol | Parameter | Units/Division |
| :---: | :---: | :---: |
| C 1 | $\mathrm{~V}_{\text {BAT }}$ | 10 V |
| C 2 | $\mathrm{I}_{\text {BAT }}$ | 500 mA |
| C 3 | $\mathrm{~V}_{\text {OUT }}$ | 20 V |
| C 4 | lout | 500 mA |
| t | time | 5 ms |

A. $\quad \mathrm{V}_{\mathrm{BAT}}$ voltage slowly increased with EN held high.
$A-B$. Input bulk capacitor $\mathrm{C}_{\text {BAT }}$ and boost output capacitor $\mathrm{C}_{\text {OUT }}$ are charged to $\mathrm{V}_{\text {UvLO }}$.
B. $\quad \mathrm{V}_{\mathrm{BAT}}$ reaches $\mathrm{V}_{\mathrm{UVLO}}$, and enables A 8501 through soft start.

B-C. During soft start period, boost switch peak current is limited to 600 mA and LED current to $1 / 20$ of desired level. Narrow current spike at $B$ is due to parasitic capacitance from OUT to ground and $\mathrm{C}_{\text {BIAS }}$. COMP pin is help low during soft start.
D. After $\mathrm{V}_{\text {OUt }}$ reaches a level such that all LED pins $\boldsymbol{>} 0.75 \mathrm{~V}$, the A8501 comes out of soft start.
C-E. After initial rise of $\mathrm{V}_{\text {OUT }}$, the capacitor $\mathrm{C}_{\text {Comp }}$ starts charging slowly ( $\mathrm{C}_{\text {comp }}$ not shown).
E. $\quad V_{\text {comp }}$ reaches desired level for stable operation.
F. A8501 and LEDs reach thermal steady state.

Turn On Using EN Pin
$\mathrm{V}_{\mathrm{BAT}}=8 \mathrm{~V}, \mathrm{~V}_{\mathrm{EN}}=0 \mathrm{~V}$ to $5 \mathrm{~V}, \mathrm{I}_{\mathrm{OUT}}=400 \mathrm{~mA}$
4 channels enabled, 6 series LEDs each


## PERFORMANCE CHARACTERISTICS

LED Current Error at 100 Hz PWM


LED Current Error at 200 Hz PWM


The LED Current Error graph shows the effect of PWM duty cycles on LED current error, according to the relationship: Error $(\%)=\left(I_{\text {ISET }} \times 960 \times\right.$ PWM Duty cycle $\left.-I_{\text {LED }}(a v)\right) /\left(I_{\text {ISET }} \times 960 \times\right.$ PWM Duty cycle $)$.
At lower PWM duty cycles, turn-on delay adversely affects LED current accuracy. This accuracy can be improved by extending the applied PWM signal by $2.5 \mu \mathrm{~s}$. For example, at 100 Hz PWM and $1 \%$ PWM duty cycle, the on-time would be $100 \mu \mathrm{~s}$. The effects of that turn-on delay could be offset by applying a $102.5 \mu \mathrm{~s}$ PWM pulse.


# 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect 

## PERFORMANCE CHARACTERISTICS

Output LED Open Protection
$V_{B A T}=12 \mathrm{~V}, \mathrm{I}_{\mathrm{LED}}=100 \mathrm{~mA}$ per LED string, $\mathrm{EN}=$ high

LED string \#1 disconnected. $\mathrm{V}_{\text {OUT }}$ increases to OVP level, and LED string \#1 is removed from regulation. The rest of the LED strings continue to function normally.


| Symbol | Parameter |  |
| :---: | :---: | :---: |
| Units/Division |  |  |
| C2 | $\mathrm{V}_{\text {BAT }}$ | 10 V |
| C3 | $\mathrm{V}_{\text {OUT }}$ | 20 V |
| C4 | $\mathrm{I}_{\text {out }}$ | 1 V |
| t | time | 100 mA |
|  |  |  |

All four LED strings disconnected simultaneously. V $_{\text {OUT }}$ increases to OVP level, and all LED strings are removed from regulation.


| Symbol | Parameter |  |
| :---: | :---: | :---: | Units/Division | C1 | $V_{\text {BAT }}$ | 10 V |
| :---: | :---: | :---: |
| C2 | V $_{\text {OUT }}$ | 20 V |
| C3 | V $_{\text {LED1 }}$ | 1 V |
| C4 | $\mathrm{l}_{\text {OUT }}$ | 500 mA |
| t | time | $100 \mu \mathrm{~s}$ |

## PERFORMANCE CHARACTERISTICS

ISET Characterization



## PERFORMANCE CHARACTERISTICS

Disconnect Switch Overcurrent Fault Timing Diagram

A. Overcurrent on disconnect switch is detected and disconnect switch latches off. Boost is turned off when $>3 \mathrm{~V}$ is detected across the disconnect switch. LEDs stop sinking current because there is insufficient voltage across them.
B. COMP pin reaches lockout level. LEDs are internally turned off and the COMP pin is discharged.
C. COMP pin reaches ground voltage, LEDs are internally turned on, in soft start mode, and boost is put into soft start mode. Boost and LEDs remain off because $\mathrm{V}_{\text {OUT }}$
is still at ground potential due to the disconnect switch being latched off.
D. User turns off EN.
E. The A8501 shuts down when EN is off for more than 131,072 clock cycles. If any other fault conditions were present prior to shutdown, such as: open LED, TSD, shorted LED, or secondary OVP, these are now cleared and the part is ready to be re-enabled.
F. User re-enables operation. A8501 enters soft start mode.
G. Soft start mode finished.

## 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect

## PERFORMANCE CHARACTERISTICS

## Fault Protection

$\mathrm{V}_{\mathrm{BAT}}=12 \mathrm{~V}, \mathrm{I}_{\mathrm{LED}}=100 \mathrm{~mA}$ per string
4 channels enabled, 8 series LEDs each
VOUT to LED1 Short
(LED Short Detect activated, causing a latched shutdown)

$\mathrm{V}_{\text {OUT }}$ to Ground Short
(Output Disconnect Switch opens to prevent any damage)


Open Schottky Diode Disconnect
(Secondary OVP activated, causing a latched shutdown)


# 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect 

## FUNCTIONAL CHARACTERISTICS

## Description

The A8501 is a multioutput WLED/RGB driver for display backlighting. It uses a boost converter architecture to generate output voltage to drive 4 channels with up to 9 LEDs per channel $\left(\mathrm{V}_{\mathrm{f}}=3.5 \mathrm{~V}, \mathrm{I}_{\mathrm{f}}=100 \mathrm{~mA}\right)$. The current-mode boost converter operates at constant frequency. The boost switching frequency can be set from 600 kHz to 2.2 MHz by an external resistor connected across FSET and AGND. The integrated boost DMOS switch is rated for 40 V at 3.6 A . This switch is protected against overvoltage, and provides pulse-by-pulse current limiting independently of boost converter duty cycle.

The A8501 has 4 well-matched current sinks, which provide regulated current through the load LEDs for uniform display brightness. All LEDx sinks are rated for 21 V to allow PWM dimming control.

## FREQUENCY SELECTION

The switching frequency on the SW pin, $\mathrm{f}_{\mathrm{SW}}$, can be set by applying the following equation:

$$
\begin{equation*}
f_{S W}=51 / R_{F S E T} \tag{1}
\end{equation*}
$$

where $\mathrm{f}_{\mathrm{SW}}$ is in $M H z$, and $\mathrm{R}_{\text {FSET }}$ is in $k \Omega$.

## LED SELECTION

Which LED strings are enabled is determined by the combined settings of the SEL1 and SEL2 pins, according to the following table:

Table 1: LED Channel Selection

| SEL1 Pin | SEL2 Pin | Enabled LEDx Outputs |
| :---: | :---: | :---: |
| Low | Low | Only LED1 |
| High | Low | LED1 and LED2 |
| Low | High | LED1, LED2, and LED3 |
| High | High | All channels |

LED strings that are connected to the A8501, but are not enabled
through the SELx pins, may cause a shutdown if the voltage on the corresponding LEDx pins exceeds $\mathrm{V}_{\text {LEDSC }}$. Refer to the LED Short Detect section for further details. Unused LEDx pins can be left open or connected to ground.
Use matched forward voltage LEDs for better efficiency.
The application circuit shown in Figure 1 is a boost converter and the output voltage is always higher than the battery voltage. Therefore, the quantity of LEDs per string should be such that the required output voltage is higher than the maximum battery voltage. If the battery voltage is higher than the output voltage, the A8501 will switch with minimum pulse width, and the actual output voltage will be higher than the required voltage. The excess voltage will be dropped across the LED strings. This lowers efficiency and increases power dissipation, resulting in higher device temperature. If battery voltage must be higher than required output voltage, use a SEPIC converter, as shown in Figure 10.

## Enabling the IC

The A8501 is enabled by pulling the EN pin to logic high, provided that VIN is above UVLO threshold, If $\mathrm{EN}=\mathrm{H}$ before VIN is applied, the IC will only startup after VIN has raised above UVLO threshold, This is illustrated by startup waveforms shown on page 9 .

## Soft-Start and Compensation

At startup, the output capacitor is discharged and the A8501 enters soft start. The boost current is limited to 0.6 A and all active LEDx pins sink $\frac{1 / 20}{}$ of the set current until all the enabled LEDx pins reach 0.75 V . When the A8501 comes out of soft start, the boost current and the LEDx pin currents are set to normal. The output capacitor charges to voltage required to supply full LEDx currents within a few cycles. Once $\mathrm{V}_{\text {OUT }}$ reaches the required level, LEDx current toggles between 0 and 100\% in response to PWM signals. Soft start behavior on evaluation boards is shown in the Performance Characteristics section.

# 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect 

## LED Current Setting

The maximum LED current can be up to 100 mA per channel, and is set through the ISET pin. Connect a resistor, RISET, between this pin and AGND to set the reference current level, $\mathrm{I}_{\text {ISET }}$, according to the following formula:

$$
\begin{equation*}
I_{I S E T}=1.235 / R_{I S E T}, \tag{2}
\end{equation*}
$$

where $\mathrm{I}_{\text {ISET }}$ is in $m A$ and $\mathrm{R}_{\text {ISET }}$ is in $\mathrm{k} \Omega$.
This current is multiplied internally with a gain of 960 , and mirrored on all enabled LED pins. This sets the maximum current through the LEDs, referred as the $100 \%$ current.

## DIMMING

The LED current can be reduced from the $100 \%$ current level by three alternative dimming methods:

- PWM dimming using the EN pin. PWM dimming is performed by applying an external PWM signal on the EN pin. When the EN pin is pulled high, the A8501 turns on and all enabled LEDs sink $100 \%$ current. The sequence is shown in Figure 2. For optimal accuracy, the external PWM signal should be in the range 100 to 300 Hz . The slight delay between PWM signal and the LED current causes an error. To compensate for the error, a small turn-on delay should be added to the PWM signal as shown on page 10 of the Performance Characteristics section. When EN is pulled low, the boost converter and LED sinks are turned off. The compensation (COMP) pin is floated, and critical internal circuits are kept active. If EN is pulled low for more than $\mathrm{t}_{\text {PWML }}$, the device enters shutdown mode and clears all internal fault registers. As an example, for a 2 MHz clock, the maximum PWM low period while avoiding shutdown is 65 ms .
- Analog dimming using the DIM pin. When the DIM pin is pulled low, the LED sinks draw $100 \%$ current; when the pin is pulled high, the LED current level drops to $25 \%$.
- Analog dimming using the VTI pin. External DC voltage can be applied to the VTI pin to control LED current. LED current varies as a function of voltage on the VTI pin. This configuration is shown in Figure 5.


Figure 2: Timing Diagram of External PWM Signal and LED Current

## LED Open Detect

When any LED string opens, the boost circuit increases the output voltage until it reaches the overvoltage protection level. The OVP event causes any LED string that is not in regulation to be locked-out from regulating the loop. By removing the open LED from controlling the boost, the output voltage returns to normal operating voltage. Every OVP event retests all LED strings.
An EN low signal does not reset the LED string regulation lock unless it shuts down the device (exceeds $\mathrm{t}_{\text {PWML }}$ ). The locked-out LED pins always attempt to sink desired current regardless of lock-out state.

## LED Short Detect

Any LED pin that has a voltage exceeding $\mathrm{V}_{\text {LEDSC }}$ will force the device to disable the boost circuit and LEDx outputs until EN shuts down the A8501 (EN low exceeds $\mathrm{t}_{\mathrm{PWML}}$ ). This protects the LEDx pins from potentially hazardous voltages when multiple LEDs are shorted in one string.

## Overvoltage Protection

The A8501 has overvoltage protection (OVP) and open Schottky diode protection.
The OVP has a default level of 19.5 V and can be increased up to 38 V by the selection of an external resistor, as shown in figure 3. When the current though OVP pin exceeds $200 \mu \mathrm{~A}$, the OVP comparator goes low. When $\mathrm{V}_{\text {OUT }}$ falls and current through the OVP pin drops below $165 \mu \mathrm{~A}$, the OVP is released.


Figure 3: Overvoltage Protection (OVP) Circuit

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The following equation can be used to determine the resistance for setting the OVP level:

$$
\begin{equation*}
R_{O V P}=\left(V_{O V P}-19.5\right) / 200 \mu A \tag{3}
\end{equation*}
$$

where $\mathrm{V}_{\mathrm{OVP}}$ is the target typical OVP level, and $\mathrm{R}_{\mathrm{OVP}}$ is the value of the external resistor, in $\Omega$.
A8501 has secondary overvoltage protection to protect internal switches in the event of an open diode condition. Open Schottky diode detection is implemented by detecting overvoltage on the SW pin. If voltage on the SW pin exceeds the device safe operating voltage rating, the A8501 disables and remains latched. The IC must shut down before it can be reenabled.

## OVERCURRENT PROTECTION

The boost switch is protected with pulse-by-pulse current limiting at 3.6 A . The output disconnect switch protects against output overcurrent. At 1 A typical, the A8501 disables. This process is detailed in the Disconnect Switch Overcurrent Fault Timing diagram in the Performance Characteristics section, page 13.

In some instances, when the LEDs are connected by long wires and also some output capacitance (such as ESD capacitors) is present, a clamping diode on the output must be used. This diode will prevent the output from momentarily going negative during a short circuit condition. The diode must be chosen such that its reverse breakdown voltage is higher than normal operating voltage and its reverse current leakage is small. Please refer to the application note Output Diode Clamping for the A8501 for more details.


Figure 4: Output Overvoltage Protection (OVP) Operation

## INPUT UVLO

When $\mathrm{V}_{\text {IN }}$ rises above the UVLO enable hysteresis $\left(\mathrm{V}_{\text {UVLO(th) }}+\right.$ $\left.\mathrm{V}_{\mathrm{UVLO}(\mathrm{hys})}\right)$, the A8501 is enabled. It is disabled when $\mathrm{V}_{\text {IN }}$ falls below $\mathrm{V}_{\mathrm{UVLO}(\mathrm{th})}$ for more than $50 \mu \mathrm{~s}$. This lag is to avoid shutting down because of momentary glitches in the power supply.

## INPUT OVLO

When $\mathrm{V}_{\text {IN }}$ rises above $\mathrm{V}_{\text {OVLO(th) }}$ for more than $50 \mu \mathrm{~s}$, the A 8501 is disabled, the boost converter shuts down instantly, and LED current falls gradually with the CAP pin capacitor. When $\mathrm{V}_{\text {IN }}$ falls below $\mathrm{V}_{\mathrm{OVLO}(\mathrm{th})}$ and EN is high, the device is reenabled.

## THERMAL DERATING

Thermal derating can be achieved by connecting an NTC thermistor between VTI and ground, as shown in figure 5 . When the A8501 is enabled and $\mathrm{V}_{\mathrm{TI}}>1.1 \mathrm{~V}, 100 \%$ current for the LEDs is controlled by the ISET and DIM pins. This is represented by the solid blue curves in figure 6 . When $\mathrm{V}_{\mathrm{TI}}$ falls below 1.1 V , $\mathrm{V}_{\text {ISET }}$ starts to follow $\mathrm{V}_{\mathrm{TI}}$, resulting in $\mathrm{I}_{\text {LEDX }}$ varying proportionately with $\mathrm{V}_{\mathrm{TI}}$ represented by the overlap of the dotted and solid curves. The proportion of $\mathrm{I}_{\mathrm{LED}}$ to $\mathrm{V}_{\mathrm{TI}}$, when LED current is controlled through the VTI pin, is calculated as:

$$
\begin{equation*}
I_{I L E D x}=960 \times V_{T I} / R_{I S E T} \tag{4}
\end{equation*}
$$

where $\mathrm{I}_{\text {LEDx }}$ is the LEDx pin current in mA , and $\mathrm{R}_{\text {ISET }}$ is in $\mathrm{k} \Omega$.
There is a hysteresis built into the VTI pin circuit, so while $\mathrm{V}_{\text {TI }}$ is decreasing, there is a delay before proportional change begins if VTI pin voltage starts above 1.1 V , as shown by the solid blue curves in figure 6 . When $\mathrm{V}_{\mathrm{TI}}$ starts below 1.1 V , or falls below 1.1 V during operation and then starts increasing again $\mathrm{V}_{\text {ISET }}$ will follow $\mathrm{V}_{\mathrm{TI}}$ until the voltage reaches 1.23 V as shown by the red-and-white dotted curves in Figure 6.


Figure 5: Thermal Derating Reference Circuit

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Figure 6: LEDx Current versus $\mathrm{V}_{\mathrm{T}}$

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## Bias Supply

The BIAS pin provides regulated 6 V for internal circuits. Connect a CBIAS capacitor with a value in the range of 0.1 to $1 \mu \mathrm{~F}$.

## Efficiency Considerations

For better efficiency, use a high quality inductor with relatively low DCR and core loss.

Use a low forward voltage Schottky diode with relatively low junction capacitance.
Use matched forward voltage LEDs for better efficiency.
The A8501 provides an output disconnect function through a load switch that is connected from the boost converter output (CAP) to LED connection (OUT). This function protects the system against short circuit conditions from common anode LED connection to ground, for both boost and SEPIC configurations.

When comparing the efficiency of the A8501 with an alternate implementation requiring an external input/output disconnect function, the additional power dissipation in this disconnect switch must be considered for a proper comparison. To bypass the disconnect switch, short the CAP pin to the OUT pin to have a direct connection from the boost regulator to the common anode LED node. When the disconnect switch is bypassed, both the boost and the SEPIC implementations are not protected against output short circuit conditions.

## Audible Noise Considerations

Multilayer ceramic capacitors cause audible noise when subjected to voltage ripple in the audio frequency range, due to the piezoelectric effect. Ceramic capacitors connected across boost converters can also cause audible noise due to voltage ripple at dimming frequencies. During the PWM dimming off-time, the voltage across the capacitors drops due to leakage through the output disconnect switch and the OVP pin. This voltage is
regulated to the desired output level during the PWM dimming on-time. This voltage ripple may cause audible noise.
Audible noise can be minimized with higher dimming frequency, but at higher dimming frequencies accuracy may be affected, as shown in the Performance Characteristics section. It is recommended to use 200 Hz for optimum performance.

Selecting a sufficiently large capacitor across the boost output can reduce voltage ripple and noise. It is observed that the audible noise below 250 mV ripple is negligible.

The value to select for a boost capacitor can be calculated using the following formula:

$$
\begin{equation*}
C \geq \frac{I_{\mathrm{lk}} \times\left(1-D_{\mathrm{FPWM} \min }\right)}{f_{\mathrm{PWM}} \times 0.25} \tag{5}
\end{equation*}
$$

where
$\mathrm{I}_{\mathrm{lk}}$ is the leakage current; select $\mathrm{I}_{1 \mathrm{k}}=165 \mu \mathrm{~A}$ at a 30 V output and $175 \mu \mathrm{~A}$ at a 40 V output,
$\mathrm{D}_{\text {FPWMmin }}$ is the minimum dimming PWM duty cycle, and $\mathrm{f}_{\text {PWM }}$ is the dimming frequency; typically 200 Hz .
For example, if the dimming frequency is 200 Hz , the minimum dimming PWM duty cycle $=10 \%$, and $\mathrm{V}_{\text {OUT }}=30 \mathrm{~V}$, then select the boost capacitor as:

$$
C=\frac{165 \mu \mathrm{~A} \times(1-0.1)}{200 \times 0.25}=3 \mu \mathrm{~F}
$$

The capacitance of ceramic capacitors drops with DC bias. Use an appropriate capacitor to get at least $3 \mu \mathrm{~F}$ at 30 V .

The selection of a ripple voltage of 0.25 V is based on a typical MLCC. This ripple level depends on the type and construction of the MLCC. Increase the boost capacitor if noise exists at 0.25 V .

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## APPLICATION INFORMATION

## Design Example

This section provides a method for selecting component values when designing an application using the A8501.

## ASSUMPTIONS

For the purposes of this example, the following are given as the application requirements:

- $\mathrm{V}_{\mathrm{BAT}}: 8$ to 18 V
- Quantity of LED channels, $\#_{\text {CHANNELS }}: 3$
- Quantity of series LEDs per channel, $\#_{\text {SERIESLEDS }}: 8$
- LED current per channel, $\mathrm{I}_{\text {LED }}: 80 \mathrm{~mA}$
- Total current all channels, $\mathrm{I}_{\mathrm{OUT}}=\mathrm{I}_{\text {LED }} \times \#_{\mathrm{CHANNELS}}$
- $\mathrm{V}_{\mathrm{f}}$ at $80 \mathrm{~mA}: 3$ to 3.4 V
- $\mathrm{f}_{\mathrm{SW}}: 2 \mathrm{MHz}$
- $\mathrm{T}_{\mathrm{A}}(\max ): 65^{\circ} \mathrm{C}$


## DIMMING

The A8501 can work with wide range of PWM frequencies. A small delay between the PWM signal and the LED current may have a noticeable effect at high PWM frequencies combined with low PWM duty cycles. For example, at 100 Hz and $10 \%$ PWM duty cycle, the PWM on-period is 1 ms . In that period, the delay causes only a $0.6 \%$ error. If the PWM frequency is 1 kHz , this error is $6 \%$. However, the error caused by the turn-on delay can be decreased by increasing the applied PWM duty cycle as shown on page 10 in the Performance Characteristics section.

## PROCEDURE

The procedure consists of selecting the appropriate configuration and then the individual component values, in an ordered sequence.

1. Identify the SEL $x$ pins to use. For 3 channels:
A. connect pin SEL2 to $\mathrm{V}_{\mathrm{TO}}$
B. connect pin SEL1 to ground
2. Connect LEDs to pins LED1 through LED3 (leave pin LED4 open).
3. Select resistor RISET (connected between pin ISET and AGND). Given $\mathrm{I}_{\text {LED }}=80 \mathrm{~mA}$ and $\mathrm{A}_{\text {ISET }}=960$, then:

$$
\begin{equation*}
R_{I S E T}=1.235 /\left(I_{L E D} / A_{I S E T}\right) \tag{6}
\end{equation*}
$$

Substituting:

$$
R_{I S E T}=1.235 /(0.080 / 960)=14.82 \mathrm{k} \Omega .
$$

Select a common value: $14.7 \mathrm{k} \Omega, 1 \%$.
4. Select resistor RFSET (connected between pin FSET and AGND). Given:

$$
\begin{equation*}
R_{F S E T}=51 / f_{S W}, \tag{7}
\end{equation*}
$$

for a 2 MHz switching frequency, select:

$$
R_{F S E T}=51 / 2=25.5 \mathrm{k} \Omega, 1 \% .
$$

5. Select resistor ROVP (connect to the OVP pin to set the OVP level, $\mathrm{V}_{\text {OUT }}(\max )$ ). Given $\mathrm{V}_{\mathrm{f}}(\max )=3.4 \mathrm{~V}, 0.75 \mathrm{~V}$ as the $\mathrm{V}_{\text {LED }}$ regulation level, and worst case output disconnect switch voltage drop, then:

$$
\begin{align*}
V_{\mathrm{OUT}}(\max )= & \left(V_{\mathrm{f}}(\max ) \times \#_{\mathrm{SERIESLEDS}}\right) \\
& +V_{\mathrm{LED}}+\left(R_{\mathrm{ODS}(\mathrm{on})} \times I_{\mathrm{LED}} \times \#_{\mathrm{CHANNELS}}\right) . \tag{8}
\end{align*}
$$

Substituting:
$V_{\text {OUT }}(\max )=(3.4 \times 8+0.75)+(4 \times 0.08 \times 3)=28.91 \mathrm{~V}$.
The switch resistance $\mathrm{R}_{\mathrm{ODS}(\mathrm{on})}$ can be found in the electrical table and is listed as worst case at $4 \Omega$ at high temperatures. To set the output OVP level to 33 V , given an $\mathrm{I}_{\mathrm{OVPH}}$ of $200 \mu \mathrm{~A}$, and $\mathrm{V}_{\mathrm{OVP}(\text { th })}=19.5 \mathrm{~V}$ :

$$
\begin{equation*}
R_{O V P}=\left(V_{O V P}-V_{O V P(t h)}\right) / I_{O V P H} \tag{9}
\end{equation*}
$$

Substituting:

$$
\begin{equation*}
R_{O V P}=(33-19.5) / 200 \times 10^{-6}=68 \mathrm{k} \Omega \tag{10}
\end{equation*}
$$

6. Select inductor L1. This should assume a maximum boost converter duty cycle, D (max), at $\mathrm{V}_{\mathrm{BAT}}(\mathrm{min})$ and $90 \%$ efficiency, $\eta$.

$$
\begin{gather*}
D(\max )=1-\left(V_{B A T}(\min ) \times \eta\right) / V_{\text {OUT }}(\max )  \tag{11}\\
D(\max )=1-(8 \times 0.9) / 28.91=75 \%
\end{gather*}
$$

Then calculate maximum switch on-time:

$$
\begin{align*}
& t_{\text {on }}(\max )=D(\max ) / f_{S W}  \tag{12}\\
& \quad=0.75 / 2 \times 10^{6}=375 \mathrm{~ns}
\end{align*}
$$

Maximum input current can be calculated as:

$$
\begin{gathered}
I_{B A T}=\left(V_{\text {OUT }}(\max ) \times I_{\text {OUT }}\right) /\left(V_{B A T}(\min ) \times \eta\right) \\
I_{B A T}(\max )=[28.91 \times(0.080 \times 3)] /(8 \times 0.9)=963 \mathrm{~mA} .
\end{gathered}
$$

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Set inductor ripple at $30 \%$ of $\mathrm{I}_{\mathrm{BAT}}$ (max):

$$
\begin{equation*}
I_{L}=I_{B A T}(\max ) \times I_{\text {Lripple }}(\text { Ideal }) \tag{14}
\end{equation*}
$$

Substituting:

$$
\Delta I_{L}=0.3 \times 963=289 \mathrm{~mA}
$$

Given, during switch on-time:

$$
\begin{gather*}
V_{B A T}(\text { min })=L \times \Delta I_{L} \times f_{S W} / D,  \tag{15}\\
8=L \times 0.289 \times 2 \times 10^{6} / 0.75, \text { and } \\
L=10.4 \mu H
\end{gather*}
$$

Select a common value: $\mathrm{L}_{\text {(used) }}=10 \mu \mathrm{H}$.
It is recommended to select an inductor that can handle a DC current level that is greater than 963 mA , at the peak current level (saturation) of $963 \mathrm{~mA}+289 \mathrm{~mA} / 2=1.11 \mathrm{~A}$. This is to ensure that the inductor does not saturate at any steady state or transient condition, within specified temperature and tolerance ranges. Inductor saturation level decreases with increasing temperature. It is advisable to use a inductor with a saturation level of 2.0 A . The inductor should have a low DC resistance (DCR) and core loss for better efficiency.
7. Select output capacitor COUT, given:

$$
\begin{equation*}
f_{P W M}=100 \mathrm{~Hz} \text {, } \tag{16}
\end{equation*}
$$

assuming $20 \%$ minimum dimming PWM duty cycle, $\mathrm{D}_{\mathrm{PWM}(\min )}$, and the maximum leakage current through the output disconnect switch at $\mathrm{V}_{\text {OUT }}=28 \mathrm{~V}$ is $165 \mu \mathrm{~A}$ and $\mathrm{V}_{\text {COUTripple }}=0.25 \mathrm{~V}$.
Select the output capacitor as:
$C_{\text {OUT }}=I_{l k} \times\left(1-D_{\text {PWM(min) }}\right) /\left(f_{P W M} \times V_{\text {COUTripple }}\right)$.
Substituting:
$C_{\text {OUT }}=165 \mu A \times(1-0.2) /(100 \times 0.25)=5.3 \mu F$.
Select $6.8 \mu \mathrm{~F}$.
The RMS current through COUT is given by:

$$
\begin{equation*}
C_{\mathrm{rms}}=I_{\mathrm{OUT}} \times\left(\frac{D(\max )+(r / 12)}{1-D}\right)^{1 / 2} \tag{19}
\end{equation*}
$$

where:

$$
\begin{align*}
& r=\Delta I_{L} / I_{B A T}(\max ), \text { and }  \tag{20}\\
& \Delta I_{\mathrm{L}}=\left(\frac{V_{\mathrm{BAT}}(\min ) \times D}{L_{(\text {used })} \times f_{\mathrm{SW}}}\right) \tag{21}
\end{align*}
$$

Substituting:
$(80 m A \times 3) \times\{[0.75+(0.3 / 12)] /(1-0.75)\}^{1 / 2}=0.422 \mathrm{~A}$
Select a capacitor with an RMS current rating greater than 0.422 A .
8. Select input capacitor CIN, given:

$$
\begin{equation*}
C_{I N}=\Delta I_{L} /\left(8 \times f_{S W} \times \Delta V_{\text {INripple }}\right) \tag{22}
\end{equation*}
$$

where $\Delta V_{\text {INripple }}$ is the input ripple voltage, which can be assumed to be $1 \%$ of $\mathrm{V}_{\text {Bat }}$. Then:

$$
C_{I N}=0.3 /\left(8 \times 2 \times 10^{6} \times 0.01 \times 8\right)=0.23 \mu F
$$

Select a $2.2 \mu \mathrm{~F}$ or higher, 35 or 50 V , ceramic capacitor, X5R or X7R grade.

The RMS current through CIN is given by:

$$
\begin{gather*}
I_{I N R M S}=\left(I_{\text {OUT }} \times r\right) /\left[(1-D) \times 12^{1 / 2}\right],  \tag{23}\\
=[(80 m A \times 3) \times 0.3] /[(1-0.75) \times 3.46]=83 \mathrm{~mA} .
\end{gather*}
$$

Select a capacitor with an RMS current rating greater than 83 mA .
9. Select the boost diode D1 (connect between the SW pins and the output). D1 should be a Schottky diode with low forward drop and junction capacitance.
The diode reverse voltage rating should be greater than $\mathrm{V}_{\text {OUT }}$. A 40 to 50 V diode rating is recommended.

The diode DC current rating should be greater than $\mathrm{I}_{\text {OUT }}$ and the peak repetitive current rating should be $>\mathrm{I}_{\mathrm{BAT}}(\max )$ $+\Delta I_{\mathrm{L}} / 2$.
10. Select the compensation capacitor CCOMP (connect between the COMP pin and ground). Typically, use a $1 \mu \mathrm{~F}$ capacitor to reduce audio hum during PWM dimming.
11. Calculate Power Loss. Calculate power loss at various operating conditions to estimate worst-case power dissipation.
A. Loss in LED drive:
$\mathrm{I}_{\text {LEDx }} \times \mathrm{V}_{\text {LEDx }}$ for one string

$$
\begin{equation*}
+\left(I_{L E D x} \times V_{L E D x}(a v)+0.75\right. \tag{24}
\end{equation*}
$$

$\times$ quantity of remaining enabled LED strings),
where $\mathrm{V}_{\text {LEDx }}$ is the regulation voltage of the LEDx pins, 0.75 V typical, and worst-case drop is mismatch due to LED $\mathrm{V}_{\mathrm{f}}$.

A good approximation for $\mathrm{V}_{\text {LEDx }}(\mathrm{av})$ is 0.8 V . This assumes that some of the remaining strings will regulate below, and some above, a value of 1.55 V . If the predicted

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LED matching is tighter, then a lower value can be used. If the predicted LED mismatch is large, then a higher value should be used. To get the complete and accurate power dissipation, the user will need to measure each individual LED pin to get the exact $\mathrm{V}_{\text {LED }}$ voltage:
$(80 \mathrm{~mA} \times 0.75)+[80 \mathrm{~mA} \times 2 \times(0.8+0.75)]=0.308 \mathrm{~W}$
B. Loss in low drop-out regulator (LDO) + bias:

$$
\begin{equation*}
P_{L D O}=V_{B A T}(\max ) \times I_{B I A S}, \tag{25}
\end{equation*}
$$

with bias current during switching 17 mA typical.
C. Boost switch conduction loss:

$$
\begin{equation*}
I_{B A T}^{2}(\max ) \times D \times R_{D S(o n)} \times\left(1+r^{2} / 12\right) \tag{26}
\end{equation*}
$$

where:

$$
\begin{equation*}
r=\Delta I_{L} / I_{B A T}(\max ) . \tag{27}
\end{equation*}
$$

D. Boost switch switching loss:

$$
\begin{equation*}
V_{\text {OUT }} \times I_{\text {BAT }}(\max ) \times\left(t_{\text {rise }}+t_{\text {fall }}\right) \times f_{S W} . \tag{28}
\end{equation*}
$$

Switch loss calculations assume negligible input gate charge on internal boost MOSFET until $\mathrm{V}_{\mathrm{G}(\mathrm{th})}$ (gate threshold), compared to the Miller charge; $\mathrm{t}_{\text {rise }}$ and $\mathrm{t}_{\text {fall }}$ are measured in the lab under full load conditions. To
approximate this value, use 5 ns for rise and fall times.
E. Diode loss:

Diode switching loss $=0.2 \times C_{d} \times V_{\text {OUT }}^{2} \times f_{S W}$,
where $\mathrm{C}_{\mathrm{d}}$ is the average junction capacitance of the Schottky diode. Then:

Diode conduction loss $=V_{f} \times I_{B A T}(\max ) \times(1-D)$
F. Inductor DCR loss:

$$
\begin{equation*}
I_{I N}^{2} \times R_{D C} \times\left(1+r^{2} / 12\right) \tag{31}
\end{equation*}
$$

G . Inductor core loss:
This value is an estimate. The default value would be 50 mW at 1 A ripple current, and then scaled based on ripple current.
H. Power loss in output disconnect switch:

$$
\begin{equation*}
P_{S W D I S C(o n)}=R_{O D S(o n)} \times I_{O U T}{ }^{2} \tag{32}
\end{equation*}
$$

If the Output Disconnect Switch On-Resistance, $\mathrm{R}_{\mathrm{ODS}(\mathrm{on})}$, is $2 \Omega$, then:

$$
P_{S W D I S C(o n)}=2 \times 0.24^{2}=0.11 \mathrm{~W}
$$

## TYPICAL APPLICATION CIRCUITS



Figure 7: Typical Circuit for Driving 2 LED Strings at Up To 35 V at 200 mA per LED String, with Thermal Derating


Figure 9: Typical Circuit with ESD Capacitors Across LEDs (CPx $\leq 10 \mathrm{nF}$ ), with Thermal Derating


Figure 8: Typical Circuit for Analog Dimming with External DC Voltage


Figure 10: Typical Circuit as SEPIC Converter (SEPIC converters can provide output voltage higher or lower than the input voltage; this topology can be used if the required output voltage level is within application input voltage range)

## PACKAGE OUTLINE DRAWING

## For Reference Only - Not for Tooling Use <br> (Reference MO-153 AET)

 Dimensions in millimeters - NOT TO SCALEDimensions exclusive of mold flash, gate burrs, and dambar protrusions
Exact case and lead configuration at supplier discretion within limits shown


Figure 11: Package LP, 28-Pin TSSOP with Exposed Thermal Pad

# 2 MHz, 4 Channel $\times 100$ mA WLED/RGB Driver with Output Disconnect 

## Document Revision History

| Revision | Date |  | Change |
| :---: | :---: | :--- | :--- |
| 5 | November 17, 2014 | Revised startup sequence. |  |
| 6 | February 7, 2019 | Product status changed to Not for New Design. |  |
| 7 | March 4, 2019 | Updated Selection Guide (page 2) |  |

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[^0]:    *Additional thermal information available on Allegro website.

